

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Application No.:

09/744,877

Confirmation No.:

8711

Filing Date:

January 29, 2001

Inventors:

Halimaoui et al.

Title:

PROCESS FOR FORMING

AN OXIDE LAYER OF

NON-UNIFORM

THICKNESS ON THE

SURFACE OF A SILICON

SUBSTRATE

Examiner:

Novacek, Christy L.

Art Unit:

2822

Atty. Dkt. No:

5310-03000

104

CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8

DATE OF DEPOSIT:

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail on the date indicated above and is addressed to:

Commissioner for Patents P.O. Box 1450

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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

It is respectfully requested that this Information Disclosure Statement be entered and the documents listed on attached Form PTO-1449 (ref. no. A1-A5) be considered by the Examiner and made of record. Copies of the listed documents are enclosed for the convenience of the Examiner.

Inventors: Halimaoui et al. Appl. Ser. No.: 09/744,877 Atty. Dkt. No.: 5310-03000

It is believed that no fees are associated with filing of this Information Disclosure Statement. Should any fees be required, the Commissioner is authorized to charge said fees to Meyertons, Hood, Kivlin, Kowert & Goetzel, P.C. Deposit Account No. 50-1505/5310-03000/EBM.

Respectfully submitted,

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Date: 12104

DIPE SCHOOL

Form PTO-1449 (modified)

List of Patents and Publications

For Applicant's Information

Disclosure Statement

(Use several sheets if necessary)

ATTY. DOCKET NO: 5310-03000

SERIAL NO: 09/744,877

APPLICANT: Halimaoui et al.

CONFIRMATION NO.: 8711

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U.S. PATENT DOCUMENTS

EXAM. INITIALS	REF. DES	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	A1	5,021,354	6/1991	Pfiester			
	A2	5,106,768	8/1998	Kuo			
			-				

FOREIGN PATENT DOCUMENTS

EXAM. INITIALS	REF. DES	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION. YES/NO
	A3	61016530	1/1986	JP			Abstract
	A4	97 41593	11/1997	WO			

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

	Soleimani et al.; "Formation of Ultrathin Nitrided SiO ₂ Oxides by Direct Nitrogen Implantation into Silicon"; <i>J. Electrochem. Soc.</i> , 1995, 42(10).

EXAMINER:

DATE CONSIDERED:

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the patent owner.